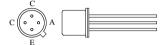
TEMIC

Optocoupler with Phototransistor Output

Description

The K120P consists of a phototransistor optically coupled to a gallium arsenide infrared emitting diode in a hermetically sealed 4 lead TO72 metal can package for high reliability requirements.



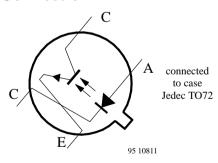
Applications

Galvanically separated circuits.

Features

- Hermetically sealed case
- High isolation resistance
- DC isolation test voltage $V_{IO} = 1000 \text{ V}$
- Current Transfer Ratio, (CTR) typical 50 %
- Coupling capacitance typical 1.5 pF
- Low temperature coefficient of CTR
- Large ambient temperature range

Pin Connection



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K120P

TELEFUNKEN Semiconductors

Absolute Maximum Ratings

Input (Emitter)

Parameters	Test Conditions	Symbol	Value	Unit
Reserve voltage		V_{R}	7	V
Forward current		I_{F}	60	mA
Forward surge current	t ≤ 10 μs	I _{FSM}	1.5	A
Power dissipation	$T_{amb} \le 25^{\circ}C$	P_{V}	100	mW
Junction temperature		T _i	125	°C

Output (Detector)

Parameters	Test Conditions	Symbol	Value	Unit
Collector-emitter voltage		V_{CEO}	35	V
Emitter-collector voltage		V _{ECO}	7	V
Collector current		I_{C}	100	mA
Power dissipation	T _{amb} ≤ 25°C	P_{V}	200	mW
Junction temperature		Ti	125	°C

Coupler

Parameters	Test Conditions	Symbol	Value	Unit	
DC isolation test voltage		V _{IO} 1)	1000	V	
Power dissipation	$T_{amb} \le 25^{\circ}C$	P _{tot}	300	mW	
Ambient temperature range		T _{amb}	-55 to +100	°C	
Storage temperature range		T _{stg}	-55 to +125	°C	
Soldering temperature	2 mm from case, $t \le 10 \text{ s}$	T _{sd}	260	°C	

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Electrical Characteristics

 $T_{amb} = 25^{\circ}C$

Input (Emitter)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Forward voltage	$I_F = 50 \text{ mA}$	V_{F}		1.25	1.5	V
Reserve voltage	tage $I_R = 100 \mu\text{A}$		7			V
Junction capacitance	$V_R = 0$, $f = 1$ MHz	Ci		50		pF
Reserve current	current $V_R = 3 V$			0.35	10	μΑ

Output (Detector)

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
Collector-emitter breakdown voltage	$I_C = 1 \text{ mA}$	V _{(BR)CEO}	35			V
Emitter-collector breakdown voltage	$I_E = 100 \mu A$	V _{(BR)ECO}	7			V
Collector dark current	$V_{CE} = 20 \text{ V},$ $I_F = 0, E = 0$	I _{CEO}			50	nA

Coupler

Parameters	Test Conditions	Symbol	Min.	Тур.	Max.	Unit
DC isolation test voltage	t = 1 min	V _{IO} 1)	1000			V
Isolation resistance	V _{IO} = 1 kV, 40% relative humidity	R _{IO} 1)	10 ¹⁰	10^{12}		Ω
I _C /I _F	$V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$	CTR	0.25	0.50		
Collector emitter saturation voltage	$I_F = 20 \text{ mA}, I_C = 2.5 \text{ mA}$ $I_F = 10 \text{ mA}, I_C = 0.5 \text{ mA}$	$egin{array}{c} V_{CEsat} \ V_{CEsat} \end{array}$		0.1	0.3	V V
Cut-off frequency	V_{CE} = 5 V, I_F = 10 mA, R_L = 100 Ω	f_g		110		kHz
Coupling capacitance	f = 1 MHz	C_k		1.5		pF

¹⁾ related to standard climate 23/50 DIN 50 014

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Switching Characteristics

 $V_S = 5 V$

Туре	$R_L = 100 \Omega$, see figure 1						$R_L = 1 \text{ k}\Omega$, see figure 2				
	t _d [μs]	t _r [µs]	ton[µs]	t _s [μs]	t _f [µs]	t _{off} [µs]	I _C [mA]	ton[µs]	t _{off} [µs]	I _F [mA]	
	K120P			5.0			3	5	11	13.8	20

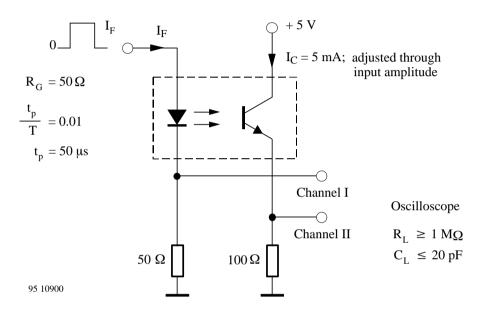


Figure 1. Test circuit, non-saturated operation

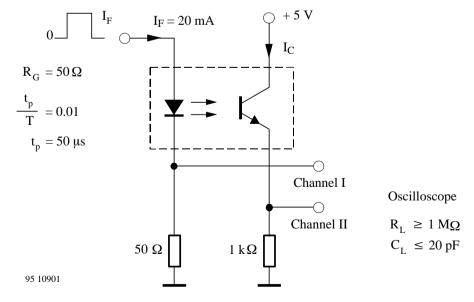


Figure 2. Test circuit, saturated operation

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Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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